FAIRCHILD SEMICONDUCTOR™

February 1984
Revised December 2003

MM74HC4020 • MM74HC4040
14-Stage Binary Counter • 12-Stage Binary Counter

General Description

The MM74HC4020, MM74HC4040, are high speed binary ripple carry counters. These counters are implemented utilizing advanced silicon-gate CMOS technology to achieve speed performance similar to LS-TTL logic while retaining the low power and high noise immunity of CMOS.

The MM74HC4020 is a 14 stage counter and the MM74HC4040 is a 12-stage counter. Both devices are incremented on the falling edge (negative transition) of the input clock, and all their outputs are reset to a low level by applying a logical high on their reset input.

These devices are pin equivalent to the CD4020 and CD4040 respectively. All inputs are protected from damage due to static discharge by protection diodes to V_{CC} and ground.

Features

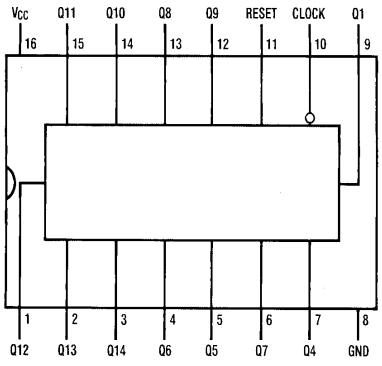
- Typical propagation delay: 16 ns
- Wide operating voltage range: 2–6V
- Low input current: 1 µA maximum
- Low quiescent current: 80 µA maximum (74HC Series)
- Output drive capability: 10 LS-TTL loads

Ordering Code:

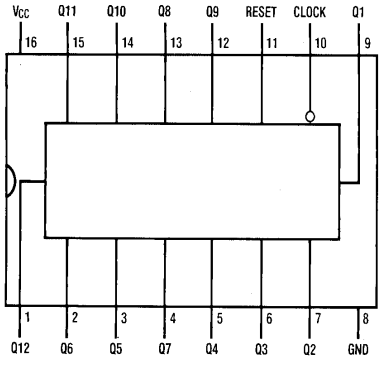
Order Number	Package Number	Package Description
MM74HC4020M (Note 1)	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4020SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4020N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC4040M (Note 1)	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4040SJ (Note 1)	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4040MTC (Note 1)	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4040N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Note 1: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams



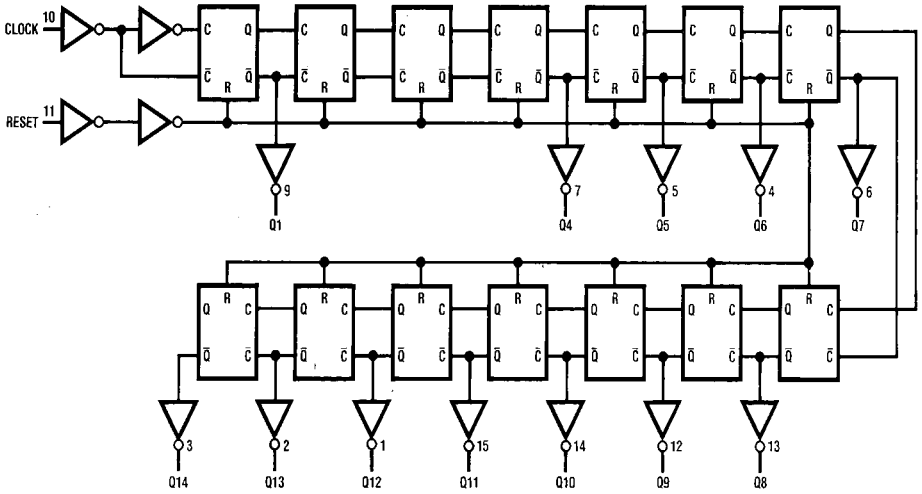
TOP VIEW
MM74HC4020



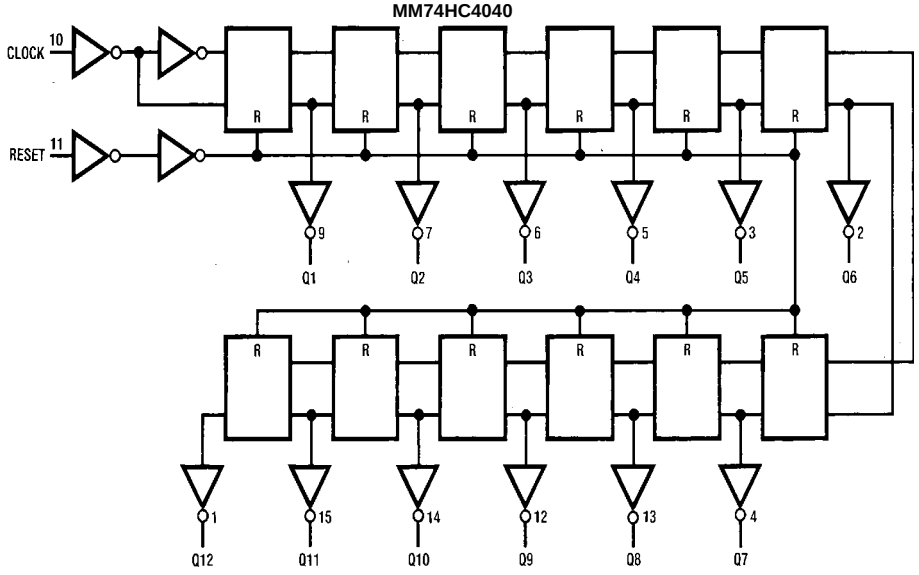
TOP VIEW
MM74HC4040

Logic Diagrams

MM74HC4020



MM74HC4040



Absolute Maximum Ratings (Note 2)

(Note 3)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{CD})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 4)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 2: Maximum Ratings are those values beyond which damage to the device may occur.

Note 3: Unless otherwise specified all voltages are referenced to ground.

Note 4: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	
			6.0V		4.2	4.2	4.2	
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	
			6.0V		1.8	1.8	1.8	
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 20$ µA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	
			6.0V	6.0	5.9	5.9	5.9	
		V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	
		$\lvert I_{OUT}\rvert \le 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 20$ µA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	
			6.0V	0	0.1	0.1	0.1	
		V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 4.0$ mA	4.5V	0.2	.26	0.33	0.4	
		$\lvert I_{OUT}\rvert \le 5.2$ mA	6.0V	0.2	.26	0.33	0.4	
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	µA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 µA	6.0V		8.0	80	160	µA

Note 5: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency		50	30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q	(Note 6)	17	35	ns
t_{PHL}	Maximum Propagation Delay Reset to any Q		16	40	ns
t_{REM}	Minimum Reset Removal Time		10	20	ns
t_W	Minimum Pulse Width		10	16	ns

Note 6: Typical Propagation delay time to any output can be calculated using: $t_P = 17 + 12(N–1)$ ns; where N is the number of the output, Q_W, at V_{CC} = 5V.

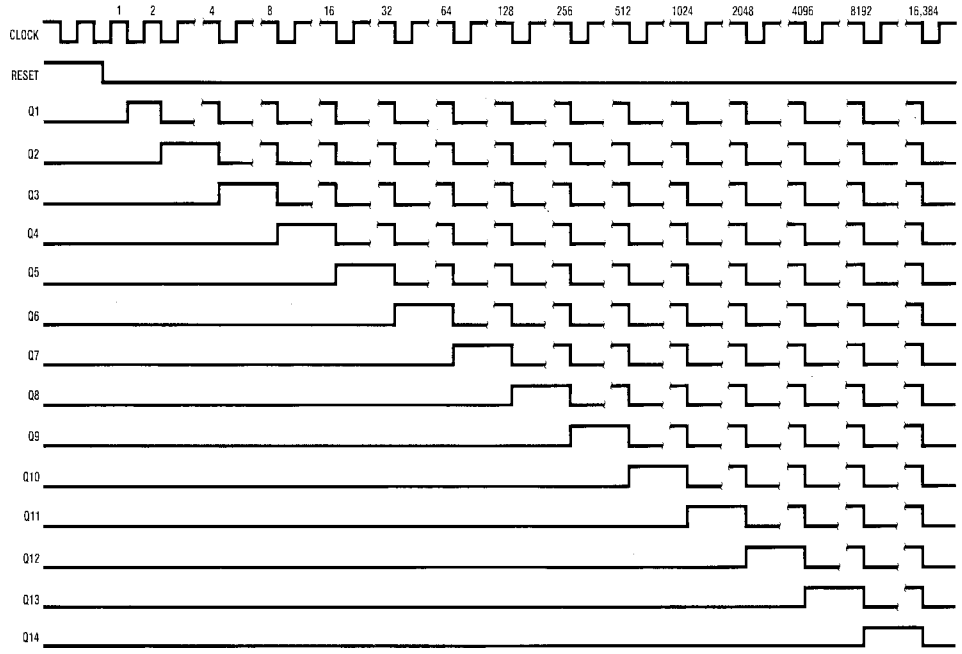
AC Electrical Characteristics

V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

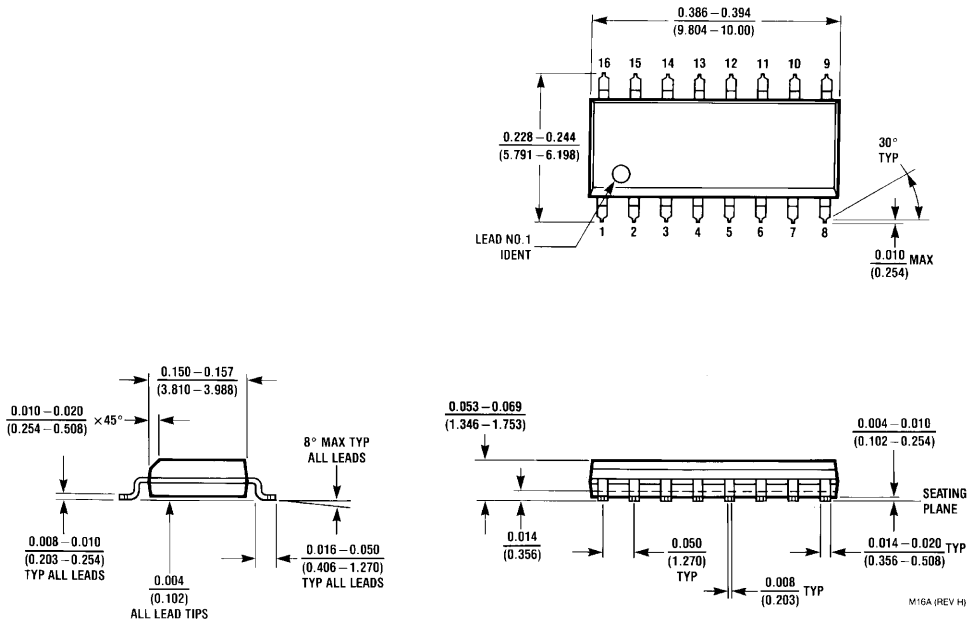
Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V	10	6	5	4	MHz
			4.5V	40	30	24	20	
			6.0V	50	35	28	24	
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q_1		2.0V	80	210	265	313	ns
			4.5V	21	42	53	63	
			6.0V	18	36	45	53	
t_{PHL}, t_{PLH}	Maximum Propagation Delay Between Stages from Q_n to Q_{n+1}		2.0V	80	125	156	188	ns
			4.5V	18	25	31	38	
			6.0V	15	21	26	31	
t_{PHL}	Maximum Propagation Delay Reset to any Q (4020 and 4040)		2.0V	72	240	302	358	ns
			4.5V	24	48	60	72	
			6.0V	20	41	51	61	
t_{REM}	Minimum Reset Removal Time		2.0V		100	126	149	ns
			4.5V		20	25	50	
			6.0V		16	21	25	
t_W	Minimum Pulse Width		2.0V		90	100	120	ns
			4.5V		16	20	24	
			6.0V		14	18	20	
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	10	15	19	22	
			6.0V	9	13	16	19	
t_r, t_f	Maximum Input Rise and Fall Time				1000	1000	1000	ns
					500	500	500	
					400	400	400	
C_{PD}	Power Dissipation Capacitance (Note 7)	(per package)		55				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 7: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Timing Diagram

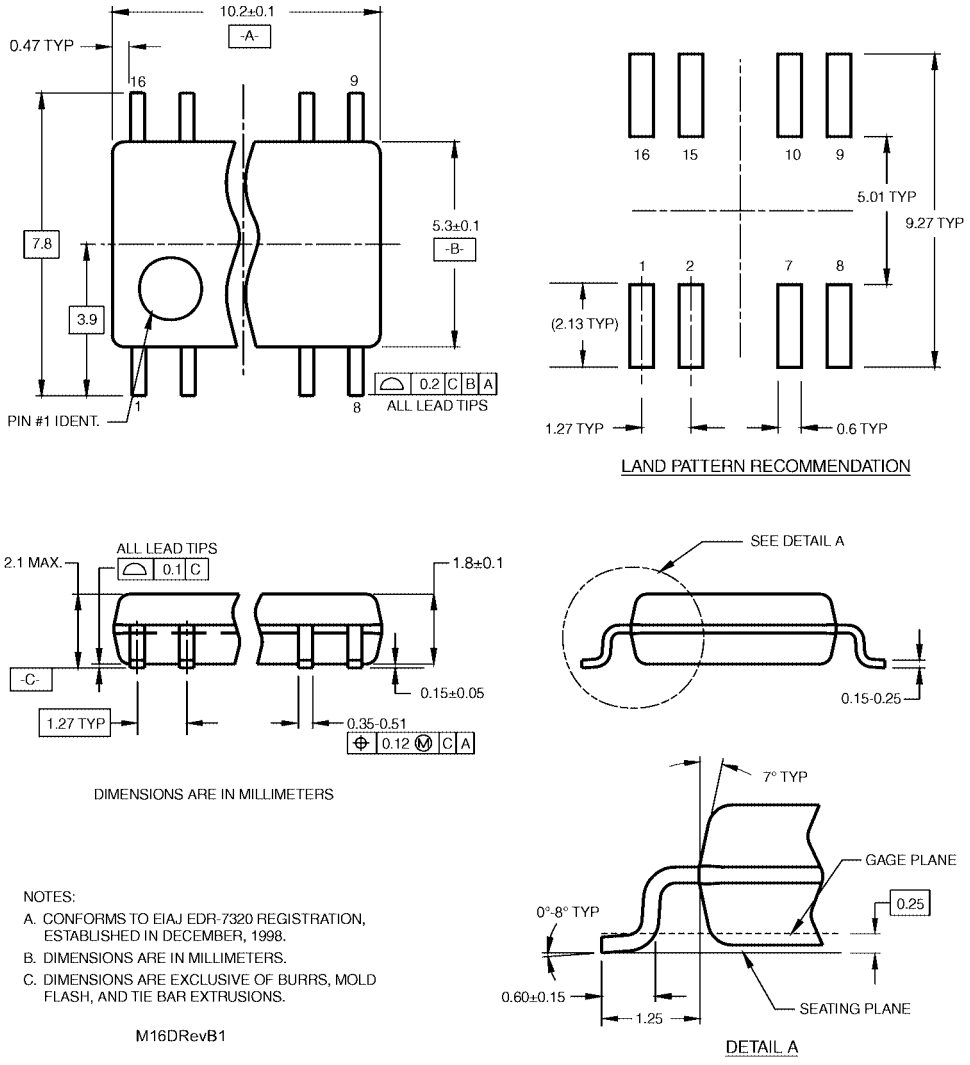


Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

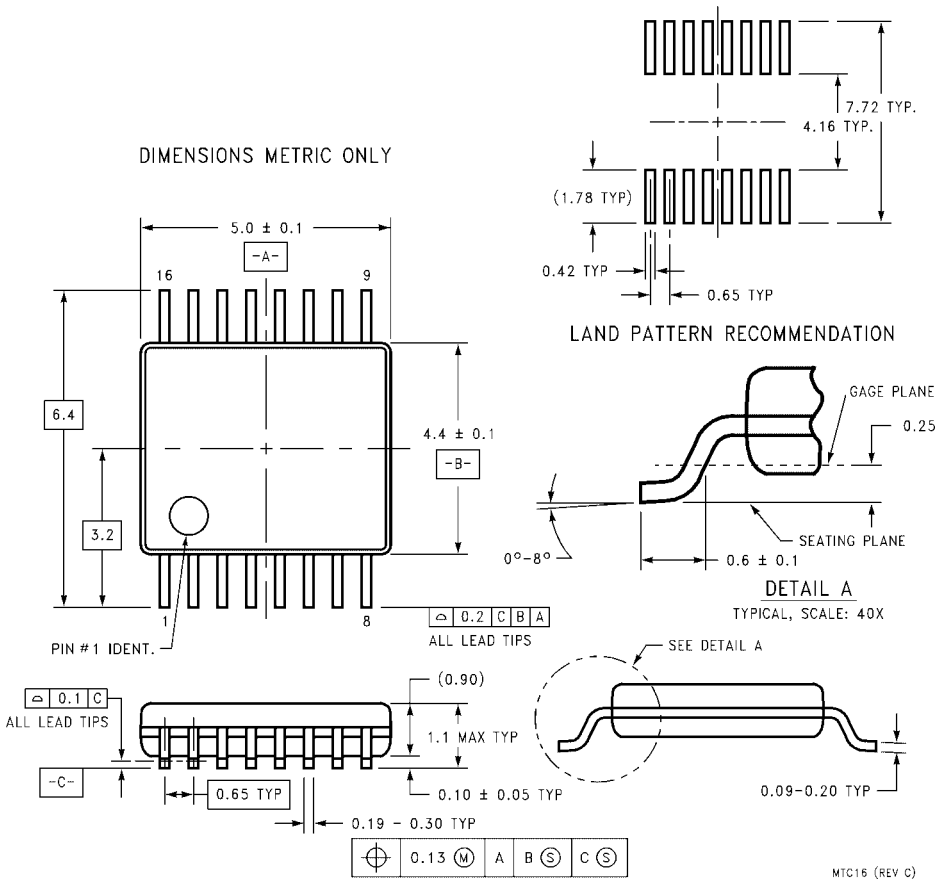
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

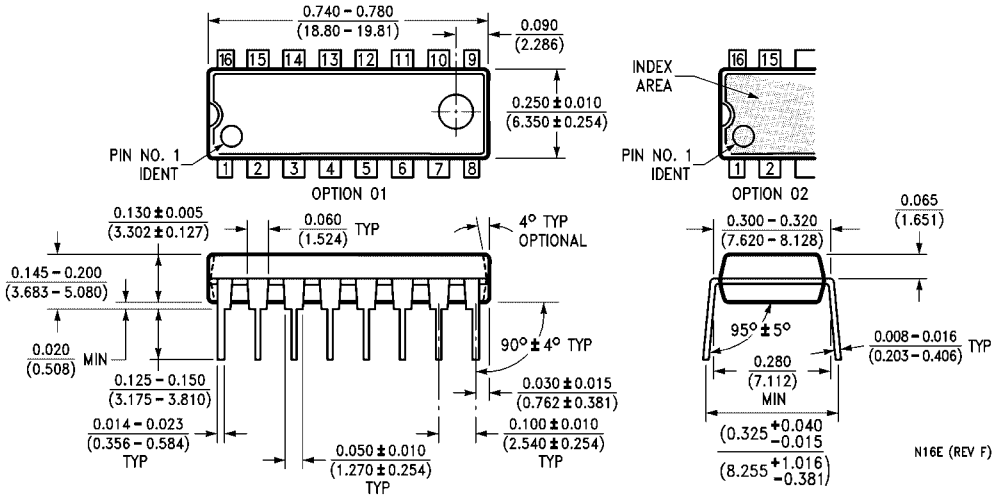
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E